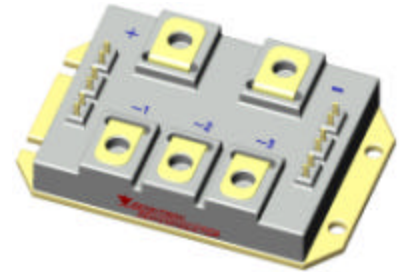


**TECHNICAL DATA**  
**PART NUMBER: SCP-5144, ENG. -**

## 3-Phase Bridge -- IGBT Module 600V, 100A

**Features:**

- Multiple Layer, Moisture and Contamination Resistant Construction
- Increased Creepage and Clearance Distances for High Altitude Operation
- Operation at Temperature Extremes
- Internal Layout with Minimized Stray Inductances
- High Frequency Switching



**Maximum Ratings** All ratings are at  $T_A = 25^\circ\text{C}$  unless otherwise specified.

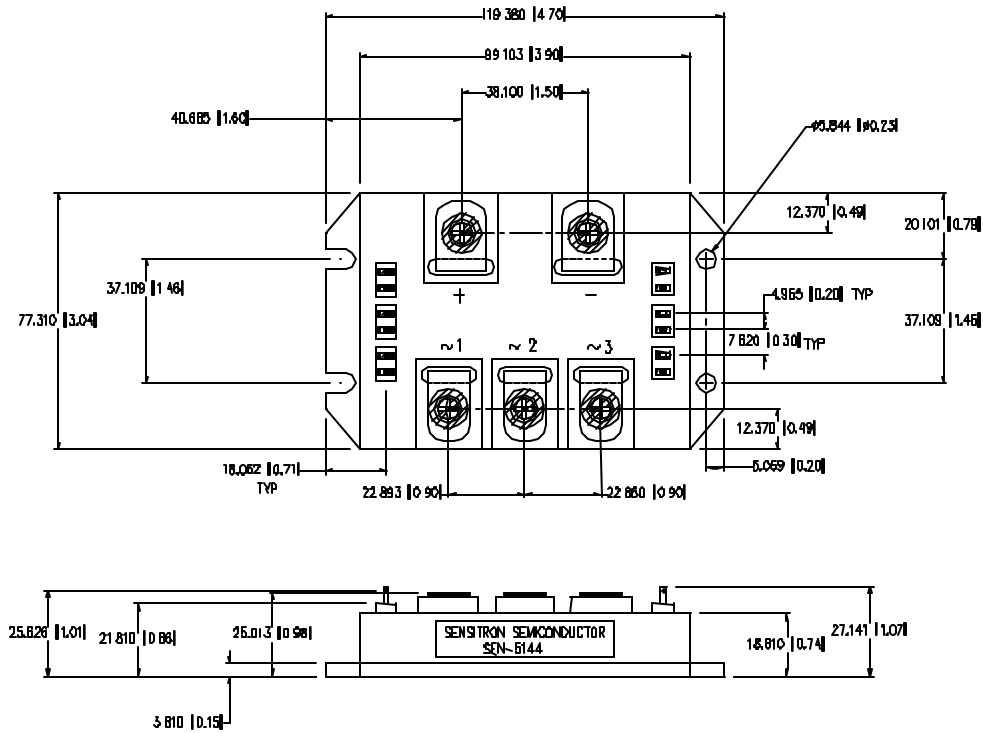
Symbol	Test Conditions	Value	Units
$V_{ces}$	$T_j = 150\text{C}$	600	V
$I_c$	$T_c = 25\text{C} / 80\text{C}$	100 / 70	A
$I_{cpulse}$	$T_c = 25\text{C} / 80\text{C}$ $F = 10\text{kHz}, D = .05, V_{ce} = 300\text{V}$	200 / 140	A
$V_{GE}$		+ / - 20	V
Hipot	1500Vrms, 50Hz / 60Hz, 1 min.	10	$\mu\text{A}$
$T_j$		-55 to 150	$^\circ\text{C}$
<b>Diode</b>			
$I_F$	$T_c = 25\text{C} / 80\text{C}$	100 / 70	A
$I_{FM}$	$T_c = 25\text{C} / 80\text{C}$ $F = 10\text{kHz}, D = .05$	200 / 140	A

**Electrical Characteristics** All ratings are at  $T_A = 25^\circ\text{C}$  unless otherwise specified.

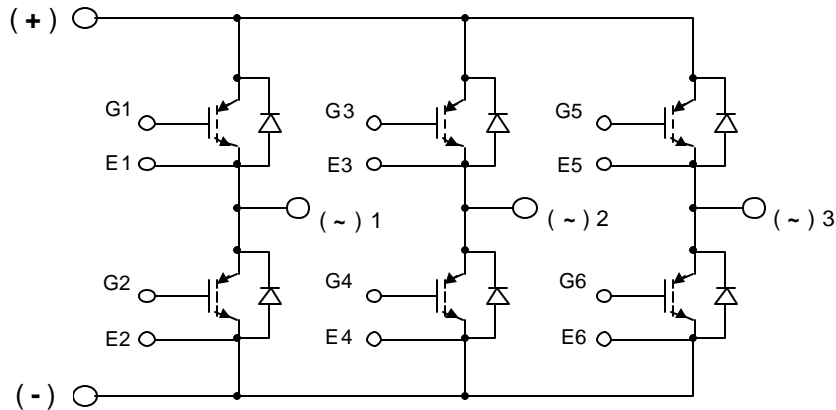
Symbol	Test Conditions	Min.	Typ.	Max.	Units
$V_{(BR)ces}$	$V_{ge} = 0\text{V}$ ,	600	-	-	V
$V_{CE(sat)}$	$V_{ge} = 15\text{V}, I_c = 100\text{A}$	-	2.0	-	V
$V_{GE(th)}$	$I_c = 1\text{mA}, V_{ge} = V_{ce}$	-	5.5	-	V
$I_{CES}$	$V_{ce} = 600\text{V}, V_{ge} = 0\text{V}$	-		-	mA
$I_{GES}$	$V_{ce} = 0\text{V}, V_{ge} = 20\text{V}$	-		250	nA
$C_{iss}$	$V_{ce} = 25\text{V}$	-	5	-	nF
$C_{oss}$	$V_{ge} = 0\text{V}$	-	1.5	-	nF
$C_{rss}$	$f = 1\text{MHz}$	-	.4	-	nF
$t_{d(on)}$	$V_c = 300\text{V}$	-	50	-	ns
$t_r$	$I_c = 100\text{A}$	-	20	-	ns
$t_{d(off)}$	$V_{ge} = + / - 15\text{V}$	-	150	-	ns
$t_f$	$R_g = 2.7 \text{ Ohm}$	-	30	-	ns
<b>Diode</b>					
$V_F$	$I_F = 100\text{A}, F = 10\text{kHz}, D = .05$		1.6		V
$t_{rr}$	$V_r = 300\text{V}$		200		ns

**SENSITRON**  
**TECHNICAL DATA**  
**PART NUMBER: SCP-5144, ENG. -**

**MECHANICAL DIMENSIONS: In Inches / mm**



**SCHEMATIC**



**TECHNICAL DATA**

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